

ISTANBUL TECHNICAL UNIVERSITY- FACULTY OF CHEMICAL & METALLURGICAL ENGINEERING DEPARTMENT OF METALLURGICAL AND MATERIALS ENGINEERING



ELECTRONIC, MA	AGNETIC,OP	TICAL PROPER	TIES OF MATERIALS	Course In	nnlomontati	on, Hours/Week	
					_		
Code	Semester	Local Credits	ECTS Credits	Theoretical	Tutori	ial Laborator	
MET 335E	5	2,5	4	2	1	-	
Department/Prog			terials Engineering		1		
Course Type		quired	Cours	se Language	ENGLIS	H	
Course Prerequi		T 246E asic Sciences	Engineering Science	Engineering	n Design	General Education	
by Content, %			60	40	, Doolgii	Conoral Education	
Course Description		This course covers :electrical conductivity and resistivity of materials, the factors affecting the conductivity of materials, metals, semiconductors and isolators, extrinsic and intrinsic semiconductors, single crystal materials, electronic device fabrication concept, electronic, optoelectronic and renewable energy devices, optical properties of materials, solder materials, printed circuit boards and solder materials, dielectric and ferro-electric materials, effects of electron configurations on the magnetic behavior of materials, classification of magnetization and magnetic materials, heat capacity, thermal expansion and thermal conductivity of materials.					
Course Objectives 1. To teach the electronic, magnetic, thermal and optical properties of engineeri 2. To make the students understand the relation between the electronic propertie electron bands of conductors and semiconductors. 3. To give an understanding of the basic electronic device theories and the processes. 4. To teach the effects of micro structure on the electronic, magnetic and optical materials.				properties and the			
After completing this course the student will be able to understand: 1. Classification of the material depending on its electron band structure and the effect microstructure and the temperature on electric conductivity, 2. Electronic – optoelectronic devices and their fabrication concepts, 3. Renewable energy devices, 4. Piezoelectric effects and the crystal structure of the piezo electric materials. The stu also will be able to use piezo electric effect equations. 5. Magnetization in the materials and the relation between the magnetic properties and electron configuration of the materials. 6. Heat capacity, thermal conduction and thermal expansion and utilize them in the rel problem solutions.				erials. The students			
Textbook	•	 Edition, McGraw – Hill, 2000, ISBN No: 0-07-116471-5. Neamen, D.A., "Semiconductor Physics and Devices: Basic Principles", 3rd ed., McGraw-Hill, 2003, ISBN No: 0-07-119862-8 White, M.A., "Properties of Materials", Oxford University Press, USA,1999, ISBN No: 					
Other Reference	•	 Design of Engineering Materials", J, McGraw-Hill, 2000, ISBN 9780072448092. Mitchell, B.S., "An Introduction to Materials Engineering and Science for Chemical and Materials Engineers", John Wiley&Sons, 2004. 					
	-	20					
Laboratory Work	noi	IC .					
Computer Use							
Other Activities		d- 4d		0	=	O !! O'	
Assessment Crit		tivities dterm Exams		Quantity MIN 1	Effects	on Grading, %	
		izzes		IVIIIN I		-	
		mework		MIN 1		5	
		ojects		-		-	
		rm Paper/Project	<u> </u>	-		-	
	La	boratory Work		-			
		ner Activities		-		-	
	Cir	al Exam		1	-	60	



${\tt ISTANBUL\ TECHNICAL\ UNIVERSITY-FACULTY\ OF\ CHEMICAL\ \&\ METALLURGICAL\ ENGINEERING}$





COURSE PLAN

Weeks	Topics	Course Outcomes
1	Periodic Table and Conductors, resistors and insulators: (Conductors, Resistors and Seeback effects, Thermistors, Polymers and Ceramics)	1
2	Semiconductors: (Intrinsic semiconductors, extrinsic semiconductors, compound semiconductors, III-V Semiconductors, Oxide semiconductors, Bulk Semiconductor Crystal Growth, Wafer Preparation)	1, 2
3	Semiconductors: (Intrinsic semiconductors, extrinsic semiconductors, compound semiconductors, III-V Semiconductors, Oxide semiconductors, Bulk Semiconductor Crystal Growth, Wafer Preparation)	1, 2
4	Semiconductors: (p-n Junction: Rectifier Diodes, Schottky Diodes and Zener Diodes, Bipolar Junction Transistors: npn and pnp transistors, FET and MOSFET, Photoconductor, MEMS – NEMS, Hall Effect Devices, Peltier Devices, Gas Sensors)	2
5	Semiconductors: (p-n Junction: Rectifier Diodes, Schottky Diodes and Zener Diodes, Bipolar Junction Transistors: npn and pnp transistors, FET and MOSFET, Photoconductor, MEMS – NEMS, Hall Effect Devices, Peltier Devices, Gas Sensors)	2
6	Semiconductors: (p-n Junction: Rectifier Diodes, Schottky Diodes and Zener Diodes, Bipolar Junction Transistors: npn and pnp transistors, FET and MOSFET, Photoconductor, MEMS – NEMS, Hall Effect Devices, Peltier Devices, Gas Sensors)	2
7	Lithography and Photo-fabrication	2
8	Optics, Optoelectronics and Lasers: (Photo detectors, LEDs, Liquid Crystal Displays, Solid State Lasers, Gas Lasers, Quantum Well Lasers, Optical Filters)	2, 7
9	Optics, Optoelectronics and Lasers: (Photo detectors, LEDs, Liquid Crystal Displays, Solid State Lasers, Gas Lasers, Quantum Well Lasers, Optical Filters)	2, 7
10	Renewable Energy Devices: (Solar Cells, Fuel Cells)	3
11	Solder Materials: (Tin-Lead Solders, Lead Free Solders, Hard Solders, Solder Pastes, Soldering Applications)Printed Circuit Boards: Printed Circuit Board Materials, Double sided and multi layer boards, Through Hole Coatings, Flexible Printed Circuit Boards)	2
12	Magnetic Materials: (Diamagnetic, Paramagnetic, Ferromagnetic, Ferrimagnetic and Anti-ferromagnetic Materials, Soft Magnets, Hard Magnets, Superconducting Magnets)	5
13	Ionic Crystals and Piezo Electricity: (Ionic crystals and ionic polarization, Piezo Electric Effect Applications) Dielectric Materials and Capacitors	4
14	Heat Properties of Materials: (Heat Conductors and thermal expansion, Bi-metals and Thermostats, Temper Glasses)	6

Relationship between the Course and METALLURGICAL AND MATERIALS ENGINEERING Curriculum

	Program Outcomes		Level of Contribution		
		1	2	3	
1	Ability to apply the knowledge of mathematics, science and engineering principles to solve problems in metallurgical and materials engineering (ABET:a)			х	
2	Ability to characterize materials using standard and/or self designed experimental methods and to evaluate the results (ABET:b)	х			
3	Ability to design a system or a process, taking into consideration of the desired specifications, quality, ethics and environment. (ABET:c)				
4	Ability to communicate both orally and in the written form and to take part in, and provide leadership of the teams in the elucidation of engineering problems; (ABET:d, g)				
5	Ability to define, formulate and solve engineering problems in the development, production, processing, protection and usage of engineering materials. (ABET:e)			х	
6	An understanding of professional and ethical responsibilities(ABET:f)				
7	An understanding of current/contemporary issues and impact of engineering solutions in broad cultural, national and global levels;. (ABET:h, j)	х			
8	A comprehension of the nature of engineering progress closely linked with the development of new materials and production processes. An ability to engage in life-long learning and a recognition of its necessity (ABET:i)		х		
9	Ability to use essential tools and techniques of modern engineering in the development, production, processing, protecting of the existing and new engineering materials. (ABET:k)			х	

1: Little, 2. Partial, 3. Full

Course relationships with major elements of the field and material classes

		Level of Contribution		
		1	2	3
	STRUCTURE			X
	PROPERTIES			X
MAJOR ELEMENT OF	DESIGN EXPERIMENT/ANALYSE DATA			
THE FIELDS	PROCESSING		х	
THE FIELDS	COST/PERFORMANCE	Х		
	QUALITY/ENVIRONMENT			
	DESIGN PROCESS OR PRODUCT		х	
	METAL			Х
MATERIAL CLASSES	CERAMICS			Х
WIATERIAL CLASSES	POLYMERS	Х		
	COMPOSITES	Х		

1: Little, 2. Partial, 3. Full

Prepared by	Date	Signature
Assoc. Prof. Dr. Kürsat KAZMANLI	March, 2013	